

XTREME

S e m i c o n d u c t o r

Chip Recovery “ChiPR” Product: Breathing New Life Into Obsolescence

In Partnership with



2015 ERAI Executive Conference

Hyatt Bayfront, San Diego CA

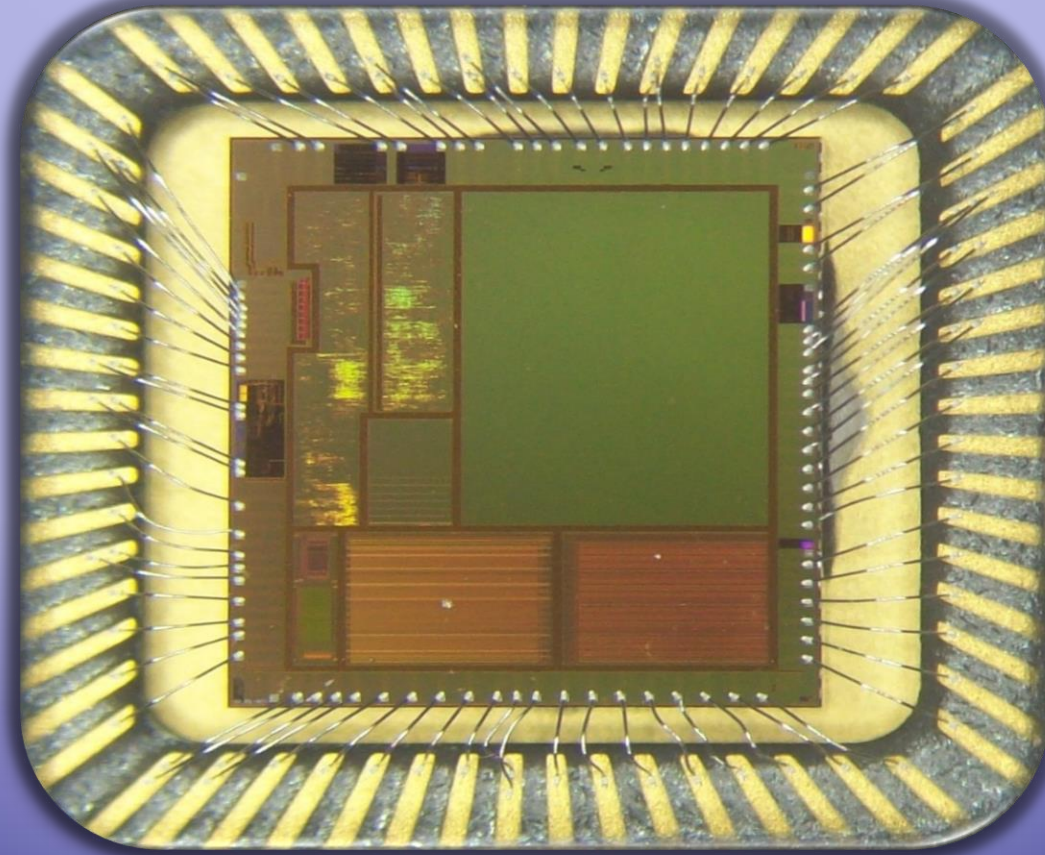
April 21-23, 2015

Presented by Marty Lanning, XTREME Semiconductor

and Erick Spory, Global Circuit Innovations

Chip Recovery “*C_{hi}PR*” Product

“Breathing New Life into Obsolescence”



Chip Recovery “C_{hi}PR” Product



Innovation

- EOL Product Support
- Solutions Company
- Manufacturing & Test

**Partners
in
Innovation
&
Technology**

Technology

- Process Development & Manufacturing
- IC Design
- Failure Analysis

What Drives Today's Component Obsolescence in Military Systems?

**Military Demand for IC's in Critical
System Designs with 20+ Year Life
Cycles**

+

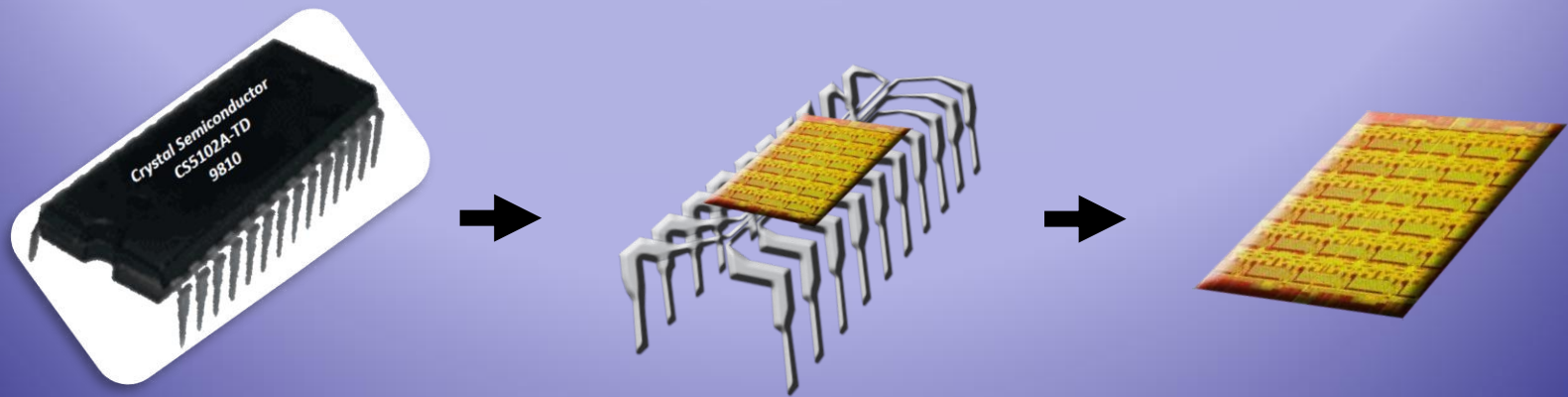
**Military Dependence on Commercial
IC's with 2-3 Year Product Life Cycles**

=

**Increasing Demand for Obsolete
Components**

What is *Chip Recovery* “*C_{hi}PR*” Product?

- Innovative Solution for Obsolete IC's
- Cost Effective Alternative Solution to other higher cost solutions such as redesign
- Semiconductor design, manufacturing, and testing programs meet or exceed Military Specs for Quality and Reliability

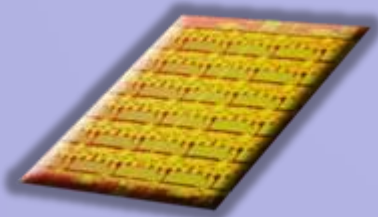


Benefits of Chip Recovery “C_{hi}PR” Product

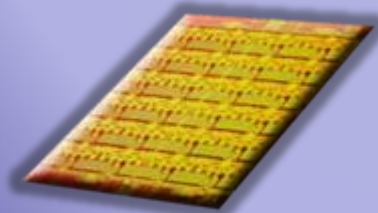
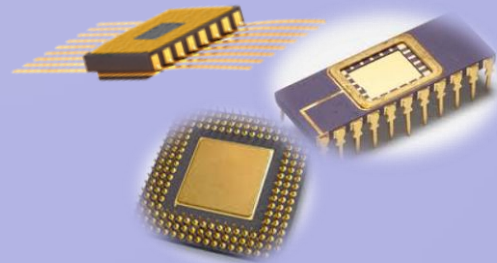
- **Access to *XTREME Semiconductor* and Global Circuit Innovations Engineering Staff, specializing in High Temperature and Obsolete part solutions**
- **Extend the life of your obsolete parts 5-10 years**
- **Eliminate the threat of counterfeit parts from entering your supply chain**



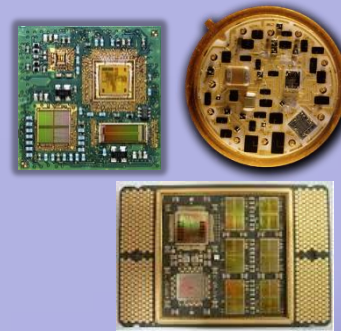
Uses for *Chip Recovery* “*C_{hi}PR*” Die



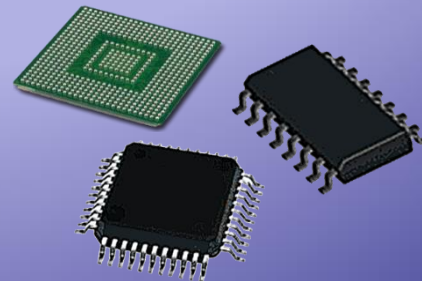
Hermetic Packaging



Hybrids & MCM's



Plastic Packaging

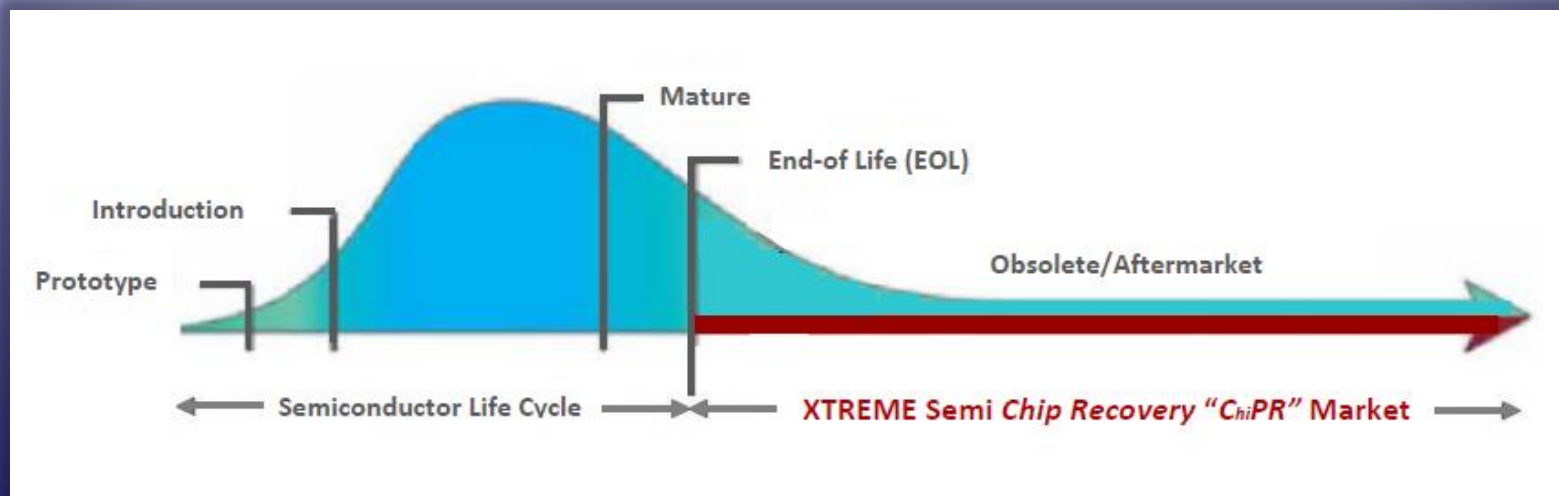


Uses for *Chip Recovery* “*ChiPR*” Product

- **Re-manufacturing of Obsolete Components**
 - Cost effective solution eliminating costly redesign
 - Guaranteed Performance of the original OCM device
- **Enhanced Performance in High Temperature Applications**
 - Industrial
 - Military
 - Down-Hole Exploration/Geophysical
- **Customized Products to Maximize Performance**

Chip Recovery: Product Standards

- ***XTREME Semiconductor*** manufactures in strict compliance with industry standard for assembly, test and qualification.
- **Manufactured to be MIL-STD-883 compatible product**
 - Manufactured on MIL-PRF-38535 QML Certified Line
 - Tested and Screened to MIL-STD-883 (processes and procedures)
- **Guaranteed to meet original OCM data sheet or specification requirements.**



Chip Recovery: Assembly, Test, & Qual

- **Ceramic & Hermetic Package Design & Assembly**
 - Monolithic, MCM, Custom Packaging
- **Screening**
 - MIL-STD-883 Compatible
 - Industrial, Military, Custom Screening Flows (SCD's)
- **Electrical Test**
 - Temperature Testing from -55° to +125°C
 - Burn In, Dynamic & Static
 - Software Development
- **Quality Conformance Inspection**
 - MIL-STD-883, Lot Qualification Group A, B, C and D

Chip Recovery “ChiPR” Product

- All *Chip Recovery “ChiPR”* product is clearly identified;
- All correspondence, including the final quote, states the product contains extracted die;
- *XTREME Semiconductor* works closely with the customer to define the appropriate qualification plan based on their application and requirements.



Successful *Chip Recovery* “*C_{hi}PR*” Product

- Solved Product Obsolescence issue for our Customer
- AD746SRC – Replacement for OP215BRC
- 79% Overall Yield Die Extraction through finished product
- Test yield attributed to commercial grade product up-screening

XT746SRC-2A MILITARY CLASS B ASSEMBLY/TEST		
Process	Description	QTY
Die extraction	AD746JRZ, 8-pin SOIC	154
Assembly	20-pin Ceramic LCC - MIL-STD-883 M5004 Class B	*149
Environmental	MIL-STD-883 M5004 (CA, TC, FL and GL)	139
Pre-Test	AD746 Data Sheet Electrical, +25C	122
Burn-in	MIL-STD-883 M5004, Test Condition 1015, 160hrs	122
Post-Test	AD746 Data Sheet Electrical, +25C	122
Final Test	AD746 Data Sheet Electrical, -55, +25 and 125C	122
* 10pcs pulled out for First Article Inspection		

Successful *Chip Recovery* “*C_{hi}PR*” Product

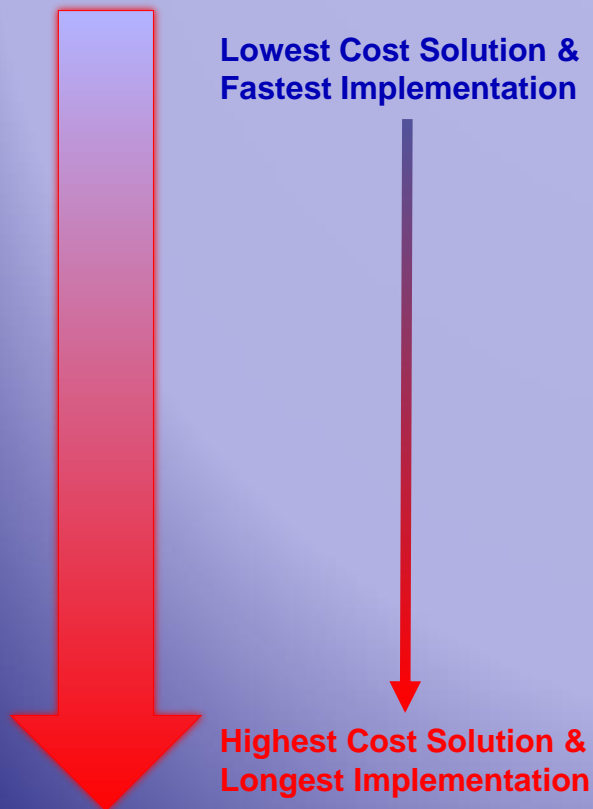
- Solved Product Obsolescence issue for customer
- ADSP1016ASE obsoleted by Analog devices
- Yield losses attributed to commercial grade product up-screening.....99% assembly/test yield

ADSP1016ASE-MT MILITARY CLASS B ASSEMBLY		
Process	Description	QTY
Die extraction	ADSP1016AJN, 16x16-bit CMOS Multilier	*252
Assembly	68-pin Ceramic LCC - MIL-STD-883 M5004 Class B	223
Environmental	Temp Cycle : MIL-STD-883 M5004, Cond.	223
Environmental	Const. Accel: MIL-STD-883 M5004, Cond.	223
Environmental	Fine Leak: MIL-STD-883 M5004, Cond.	223
Environmental	Gross Leak: MIL-STD-883 M5004, Cond.	223
Electrical Test	Test perfomred at -55 to +125C	221
Final	QC Inspection, 220pcs shipped to customer	220
* 5pcs used as assembly set-up samples		
* 18pcs failed M5004 Class B die visual however accepted as commercial grade product		
* 5pcs used for first article inspection.		
* 2pcs failed electrical test at Military temps, passed 25C testing		

Other Successful Die Extraction Products

Part Type	Function	Part Type	Function
K6R4008V1C	4M SRAM	IXDD609S1A	MOSFET Driver
K9F5608OUA	8M Flash	MTP10N10M	N-Channel MOSFET
ADLX345	Accelerometer	CZT3120	NPN Switch
BMA250	Accelerometer	OP221GSZ	Op Amp
CS5102A-TEB	AD Converter	OPA2340	Op Amp
LP1114FBD48	ARM Flash MCU	OPA678AP	Op Amp
AD746	Bi-FET Op Amp	OPA684	Op Amp
ADSP1016AJN	CMOS Multiplier	THS31001CD	Op Amp
MCP6568	Comparator	THS4522	Op Amp
EN175	Custom ASIC	EL51661SZ	Op Amp
TMS320C6657	DSP	LT1019ACN8-2.5	Precision Reference
AT28C16	EEPROM	TC25C25	PWM Controller
S87C752	EPROM	SST25VF063C	Serial Flash
M1A3PE3000L-FGG	FPGA	ADG1219BRJZ	SPDT Switch
XCV800-6BG560	FPGA	EF6840CM	Timer
A500K130	FPGA	UCC2581	Voltage PWM
EF6821JV	I/O Controller	REF5025	Voltage Reference
SN65LVDM176	Line Transceiver	MAX6350	Voltage Regulator
ISL88705	Micro Supervisor	TLV70233DBVR	Voltage regulator
MC6809CM	Microprocessor	ICL8038CCPD	Waveform Generator

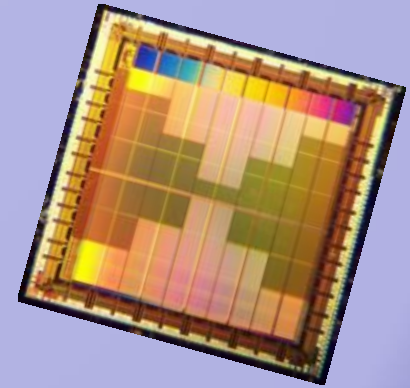
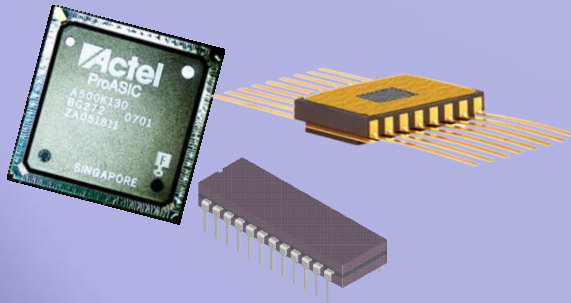
Analysis of System Redesign Options



- **Original OCM Product Available**
- Value Ranking of Available Options
- **\$ - Chip Recovery Product “*C_{hi}PR*”**
 - **\$\$ - Fabricate New Original OCM Chips**
 - **\$\$\$ - Board Redesign**
 - **\$\$\$\$ - Emulation/Reverse Engineer**
 - **\$\$\$\$\$ - New System Design**

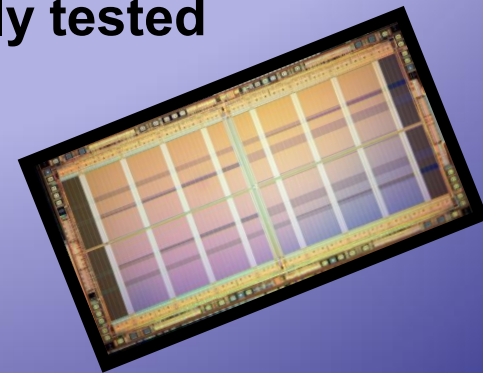
Chip Recovery “ChiPR”: Processes

- Removes die from a package undamaged, maintaining original electrical characteristics



- Can be performed on any package type

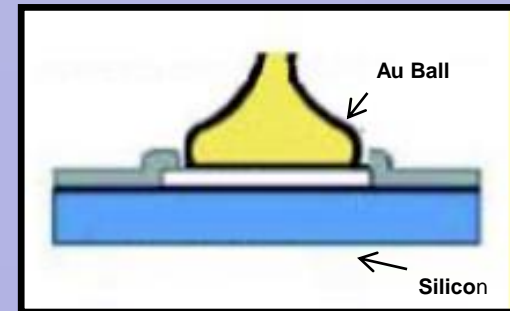
- Results in a “Known-Good” electrically tested die, ready for reassembly
 - Die thinning may also be achieved



Chip Recovery: Bond Pad Preparations

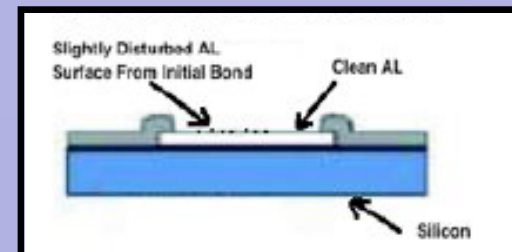
1. Re-Bonding:

- Wire dressing leaving original Gold Ball bond remnant, allowing for subsequent Gold Ball re-bonding



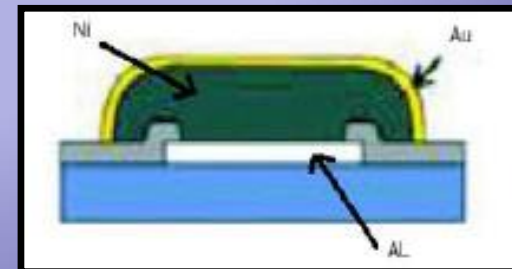
2. Bond Pad Cleaning:

- Gold Ball removal followed by Aluminum Pad cleaning, allowing for Gold Ball or Aluminum Wedge bond

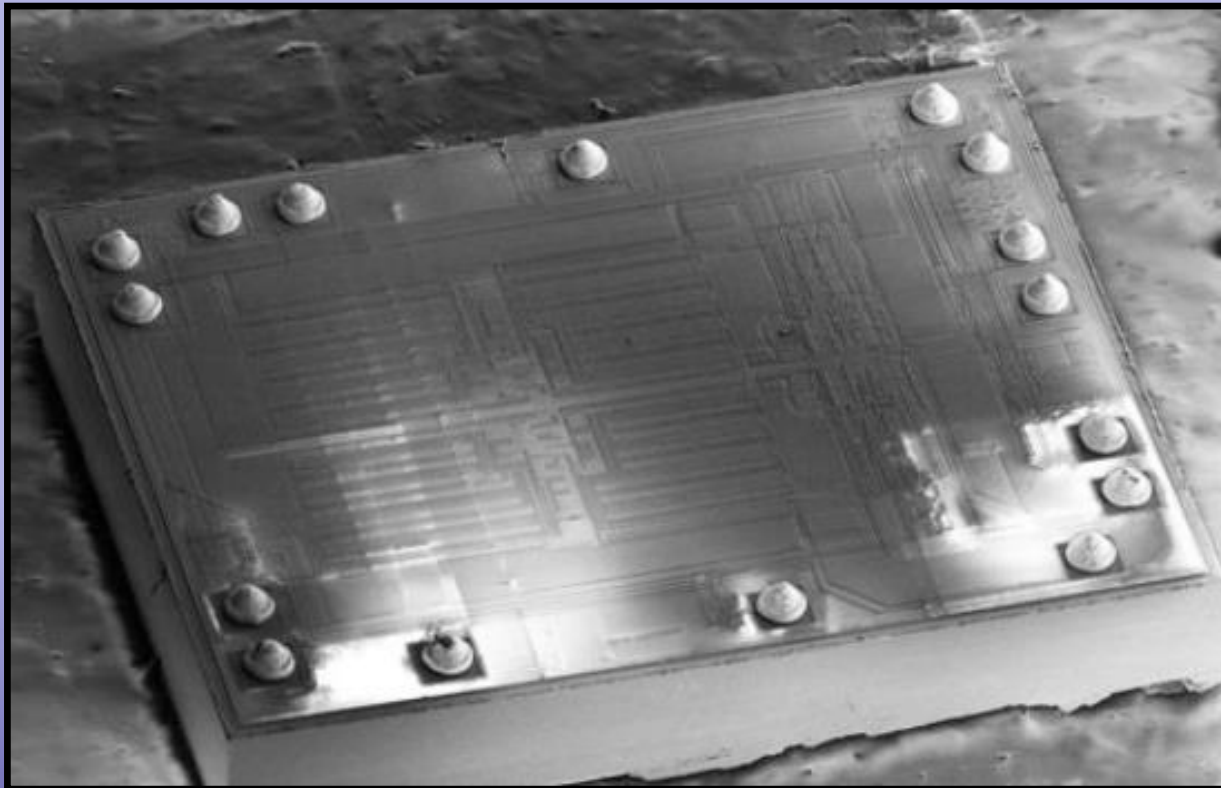


3. Pad Re-Conditioning:

- Gold Ball removal, Aluminum Pad cleaning, followed by Nickel/Au pad build up and re-plate



Chip Recovery: Bond Pad Re-bonding



Chip Recovery Die ready for re-bonding

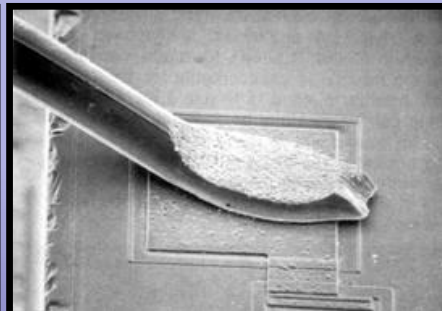
Chip Recovery: Bond Pad Re-bonding

■ Wire Bonding

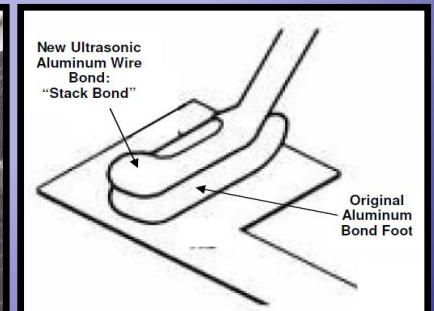
- Original Gold or Aluminum wires are mechanically removed at the top of the original bond
- Clean, uncontaminated gold or aluminum surface is used for the new, high-adhesion wire connection
- New bond formation is made to original pristine bond, NOT a re-bond.



Original Gold Ball and Aluminum Wedge Bonds



Compound Gold Ball and Aluminum Wedge Bonds



Chip Recovery: Bond Pull Data

■ Bond Pull Results

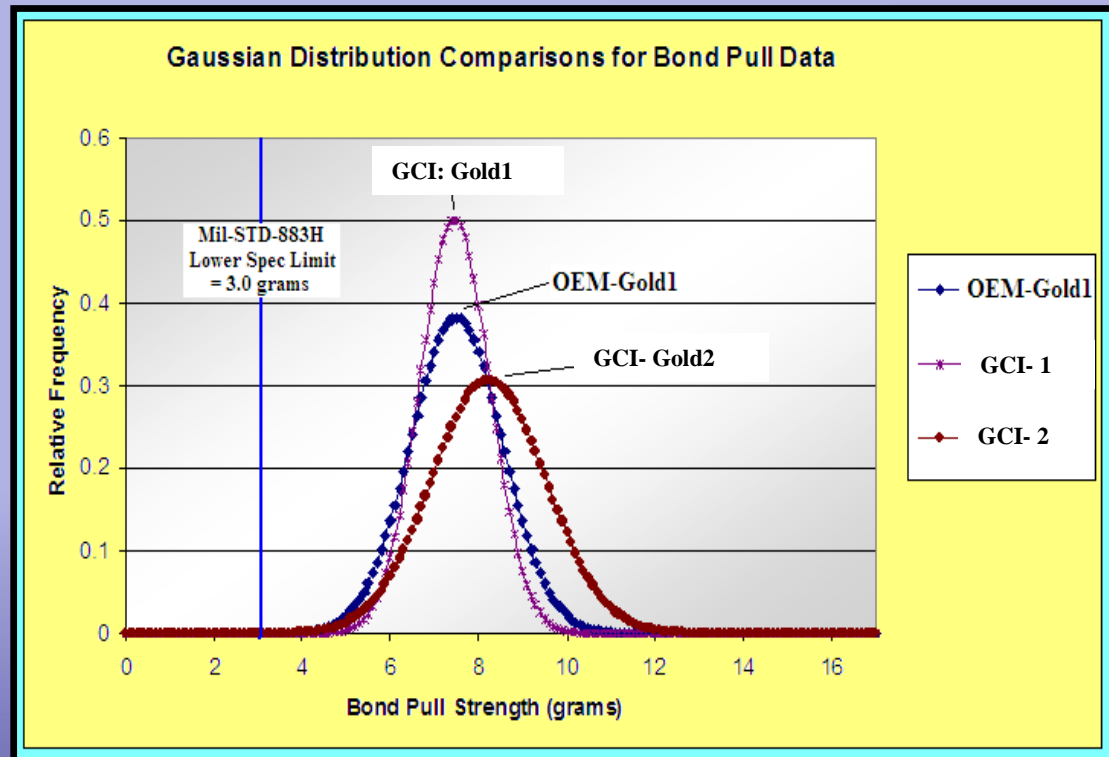
- The compound Gold on Gold Wire Connection provides identical bond pull adhesion strength to the OEM device
- The Bond Pull Data is nearly Indistinguishable for Pre and Post Die Extraction

■ Mean: 3 Sigma

- OEM Gold1 = 4.374 g
- GCI Gold1 = 5.075 g
- GCI Gold2 = 4.342 g

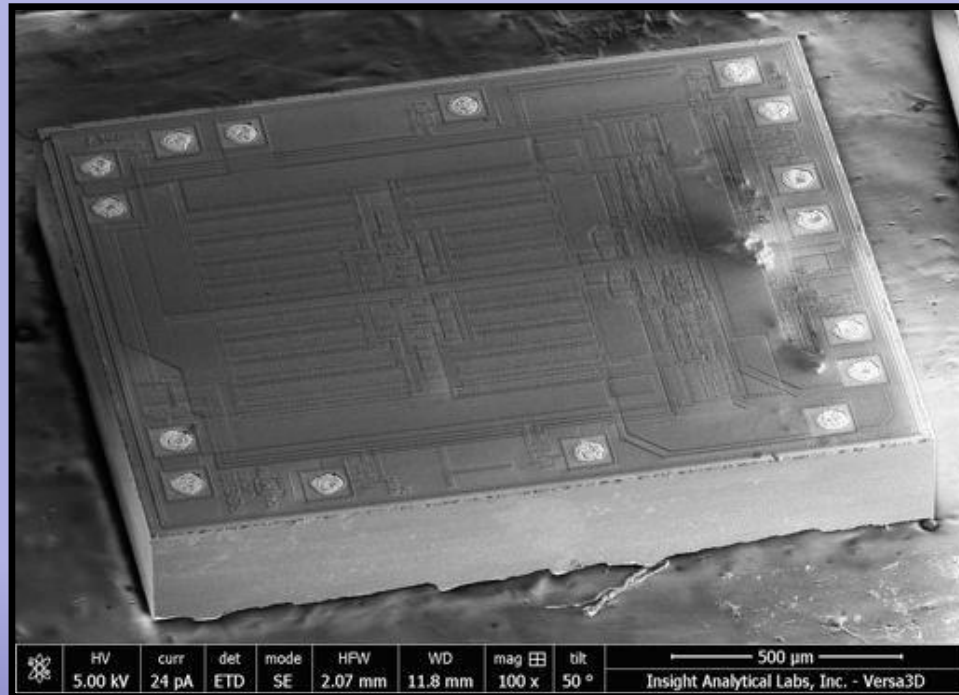
■ MIL-STD-883H

- Spec Limit = 3.0 g



Data from Global Circuit Innovations

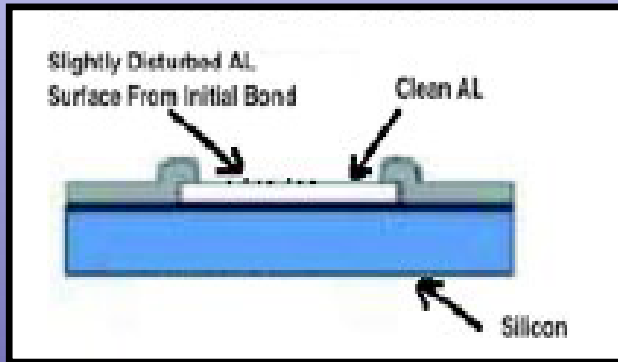
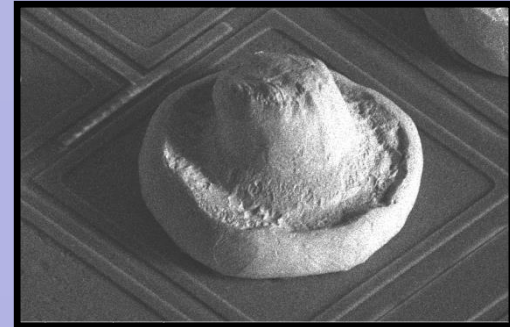
Chip Recovery: Bond Pad Cleaning



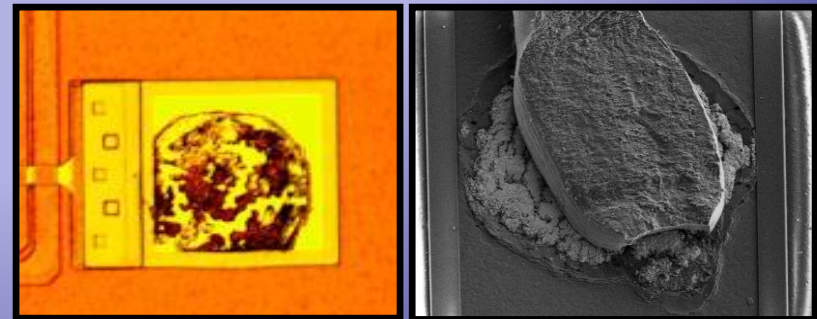
Chip Recovery Die with Remnant Bond Wires Removed and Pads Cleaned

Chip Recovery: Bond Pad Cleaning

1. Original Gold Ball bond

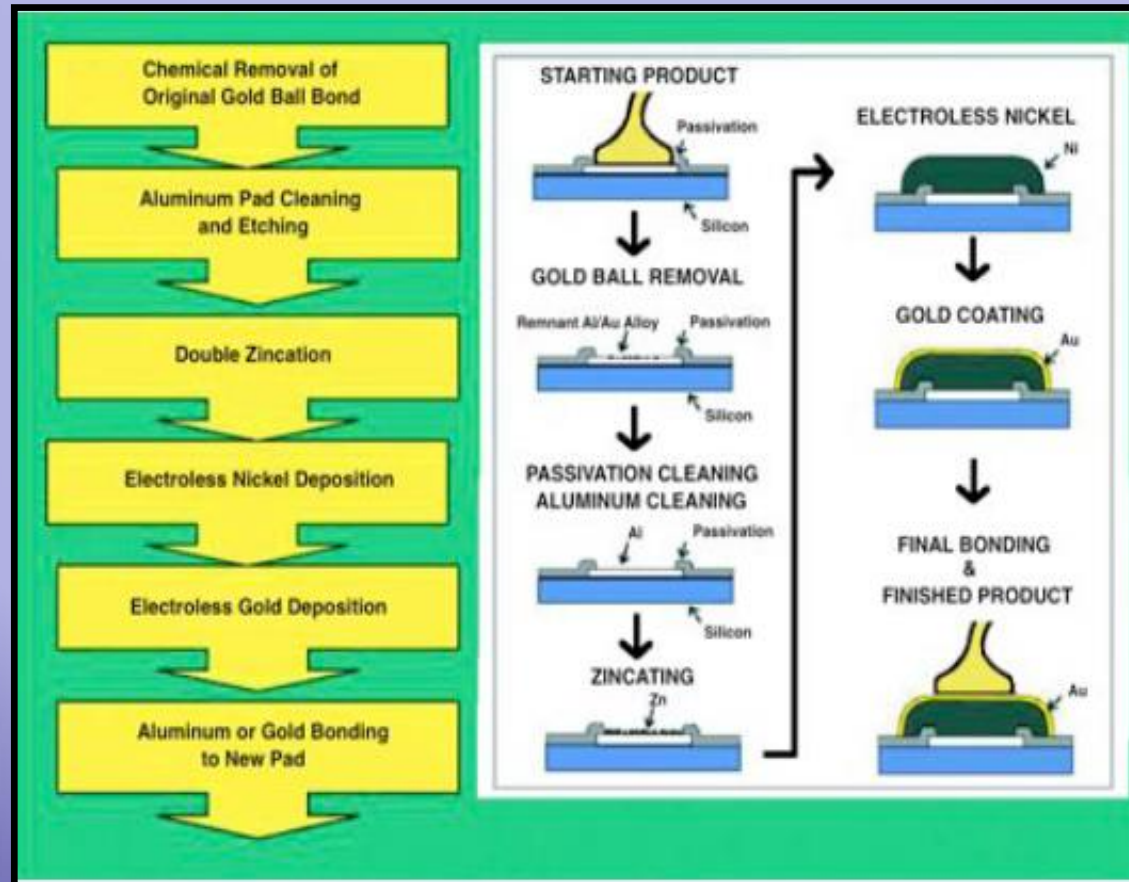


2. After removal of Gold Ball bond



3. New bonding area ready for new Gold Ball or Aluminum Wedge bonding

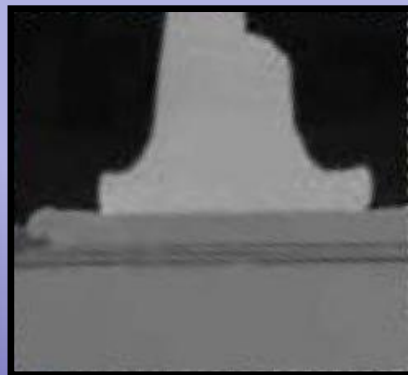
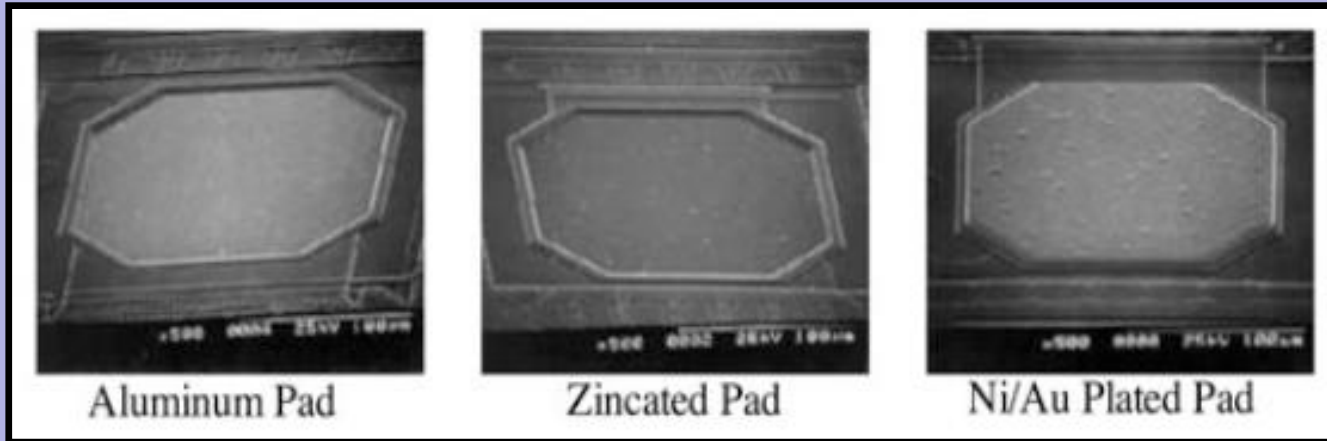
Chip Recovery: Bond Pad Reconditioning



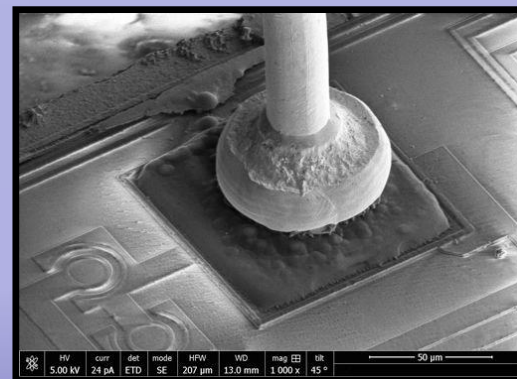
Nickle/Au Metallization UBM (Under-Bump Metal) Process

Chip Recovery: Bond Pad Reconditioning

Ni/Au Metallization UBM process



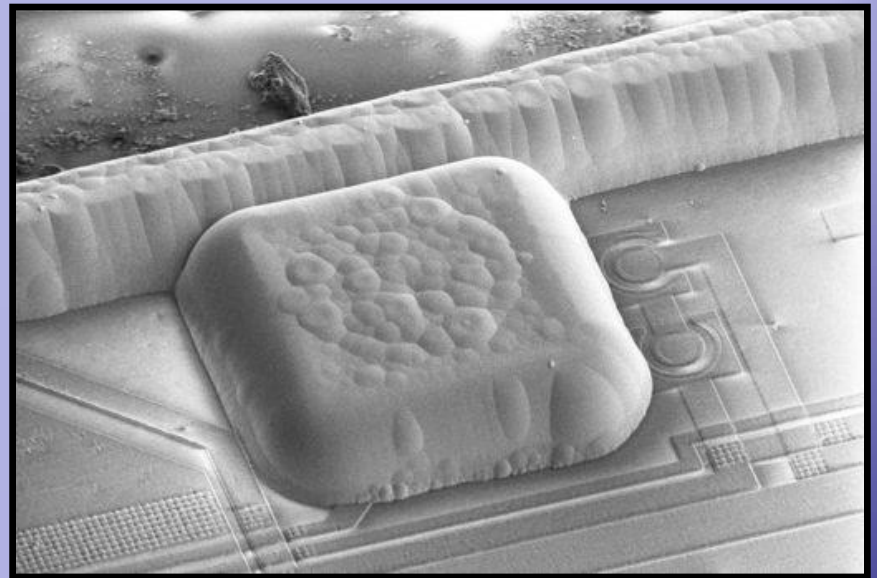
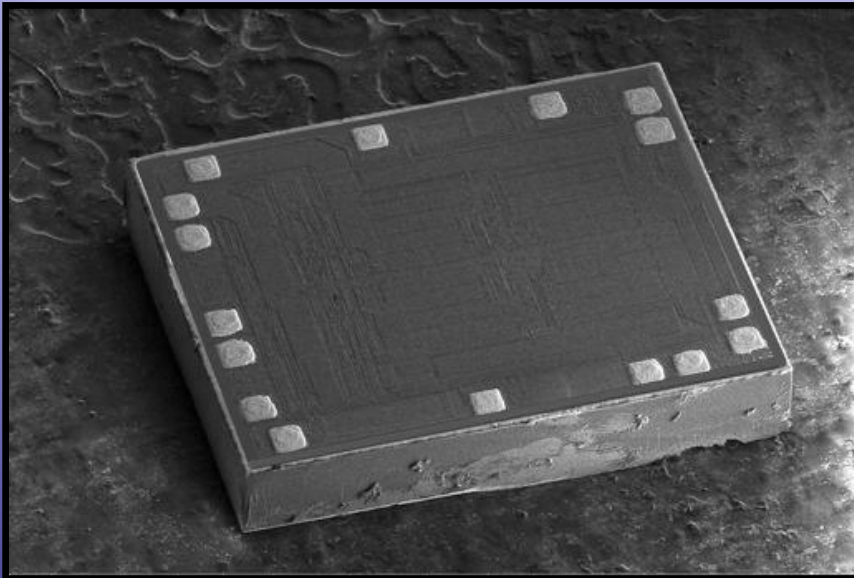
Cross Section of Au Bond and new Ni/Au Pad



Gold Ball Bond on new Ni/Au Pad

Chip Recovery: Bond Pad Reconditioning

Ni/Au Metallization UBM process



**Reconditioned Bond Pads ready for Gold Ball or
Aluminum Wedge Bonding**

Chip Recovery: Bond Pad Reconditioning

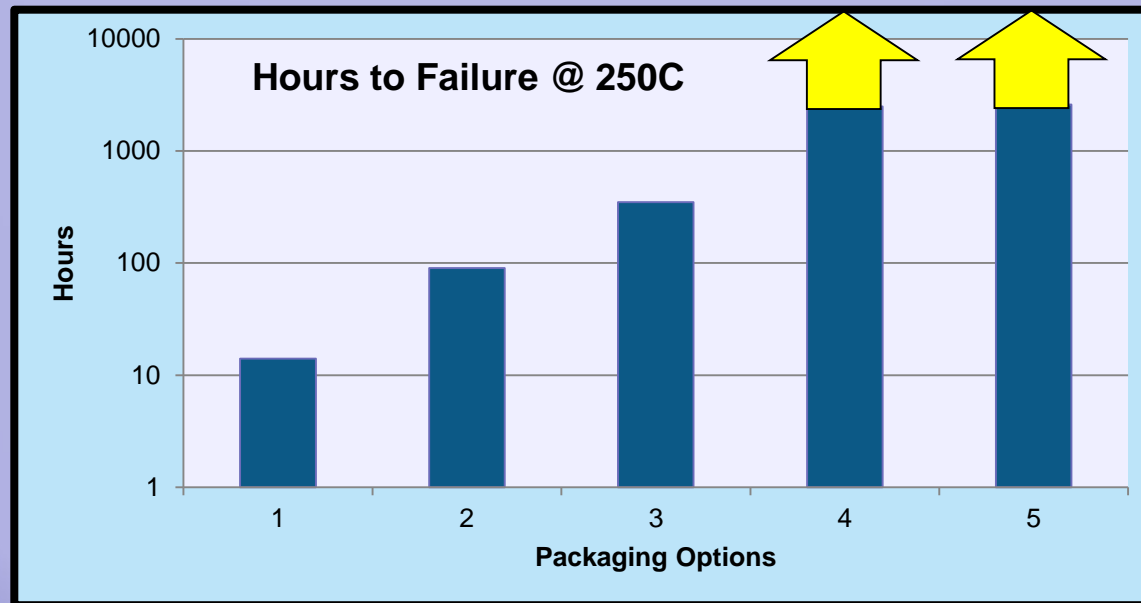
Ni/Au Metallization UBM process

Why consider our Gold Ball removal and Ni/Au Metallization UMB process?

- **Eliminates MIL-STD compound bonding concerns and provides bare die with a consistent, predictable bonding surface.**
- **Proven to provide superior bond strength if original bonding has not been optimized.**
 - **Conventional Bond Strength: Mean 3 SD = 4.01g**
 - **Ni/Au Metallization UBM Process: Mean 3 SD = 8.74g**
- **The new Ni/Au bonding interface dramatically reduces Inter-Metallic Diffusion (Kirkendall Voiding), therefore, creating a much more robust bonding process relative to high temperature (>175C) exposures.**
- **Provides new metallization compatible with High Reliability and small pitch Gold Ball bonding requirements.**

Chip Recovery: Bond Pad Reconditioning

Ni/Au Metallization UBM process



Packaging Option Key

1. Standard Plastic Packaged Product
2. Die Recovery, Standard Ceramic Assembly
3. Die Recovery, High-Temp Ceramic Assembly
4. Die Recovery with Ni/Au Reconditioned bond pads, High-Temp Ceramic Assembly
5. Die Recovery with Ni/Au Reconditioned bond pads, Standard Ceramic Assembly

Data from Global Circuit Innovations

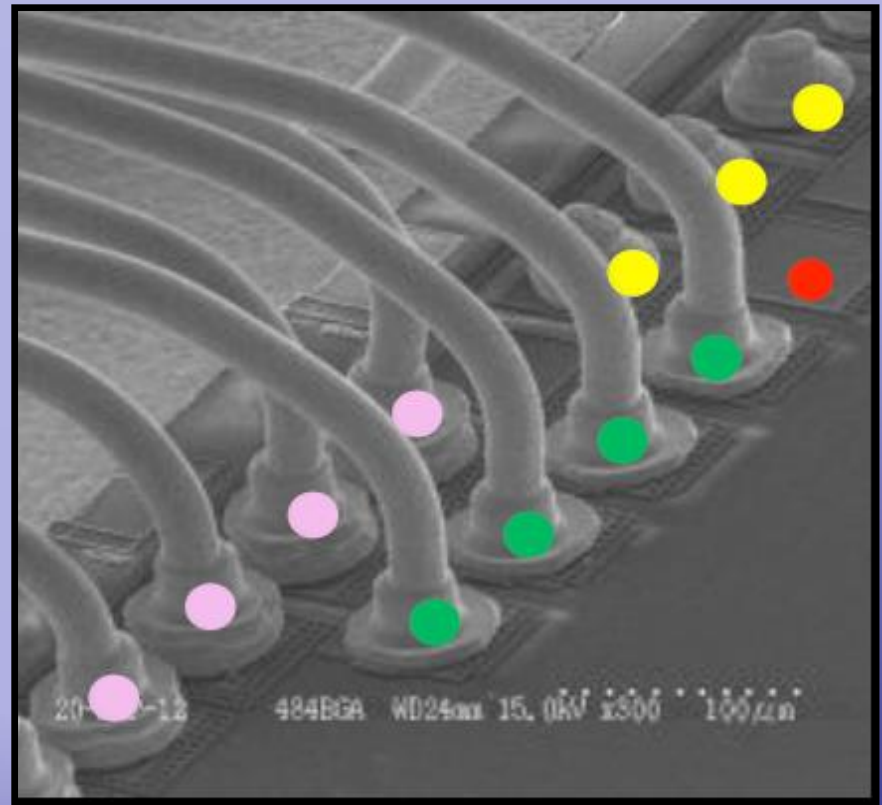
Chip Recovery: Bond Remapping and Reassembly Options

Multiple Device configurations for the same chip can be achieved with remapping optional bond outs.

- Memory Devices: Bond options for x4, x8, x16 devices from the same chip
- FPGA's: Reconfigure to create multiple devices from a single chip

Examples of Remapping Options

- Original non-bonded pad, still not bonded
- Original non-bonded pad, now bonded
- Previously bonded pad, now not bonded
- Previously bonded pad, re-bonded with new compound bond.



Chip Recovery “*C_{hi}PR*” Product

■ Benefits of *Chip Recovery*

- *Chip Recovery* and re-assembly is an excellent solution to IC Component Obsolescence – Solves DMSMS problems.
- Die can be removed from virtually ANY plastic or ceramic package without damaging the die, while maintaining FULL functionality.
- *Chip Recovery* allows fully functional die to be re-assembled into ANY plastic or ceramic package, MCM, or hybrid module
- Die Shear and Bond Pull data are identical to or exceed original OCM product.
- Allows access to original OCM die stock, while avoiding costly minimum order die or wafer purchases.
- Offers a direct replacement for the original OCM product

Chip Recovery “C_{hi}PR”

“Breathing New Life into Obsolescence”

Any Questions?

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